



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
20V	0.99Ω @ V _{GS} = 4.5V	0.55A
	1.2Ω @ V _{GS} = 2.5V	0.50A
	1.8Ω @ V _{GS} = 1.8V	0.41A
	2.4Ω @ V _{GS} = 1.5V	0.35A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- **Power Management Functions**
- Analog Switch

X2-DFN0606-3





Bottom View

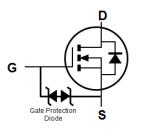


Features and Benefits

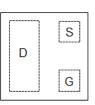
- Low Package Profile, 0.42mm Maximum Package Height
- 0.62mm × 0.62mm Package Footprint
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Maximum
- **ESD** Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: X2-DFN0606-3 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.001 grams (Approximate)



Equivalent Circuit



Top View Package Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2991UFZ-7B	X2-DFN0606-3	10k/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony free, "Green" and

Lead-free.

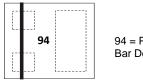
Notes:

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimonv compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

X2-DFN0606-3



94 = Product Type Marking Code Bar Denotes Gate and Source Side

Top View



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current (Note 5) V_{GS} = 4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +75^{\circ}C$	ID	0.55 0.44	A
Maximum Body Diode Forward Current (Note 6)			Is	0.7	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)			I _{DM}	1.5	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)	Steady State	PD	0.45	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	279	°C/W
Power Dissipation (Note 6)	Steady State	PD	0.53	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{θJA}	148	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

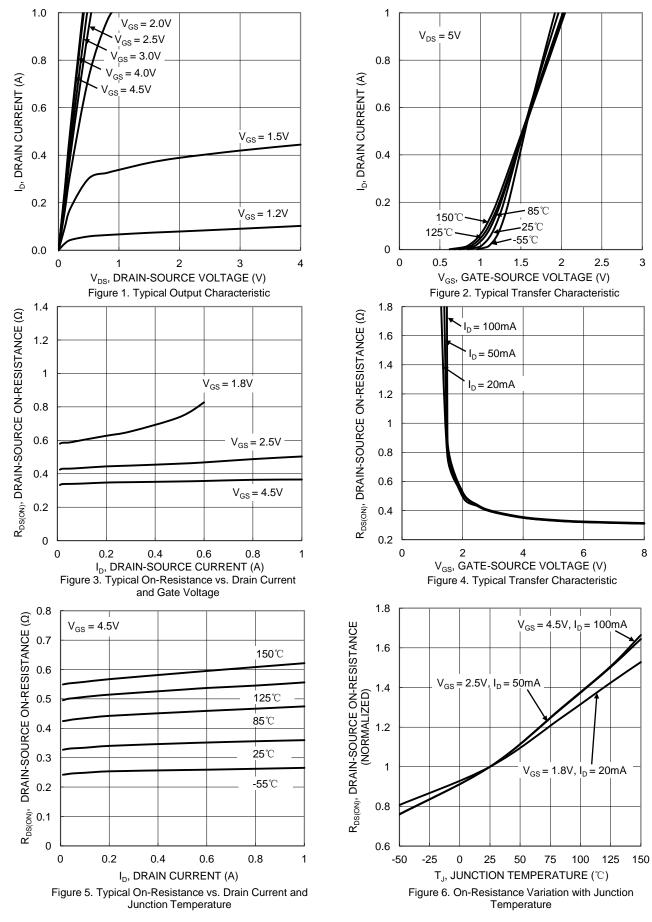
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}		_	1	μA	$V_{DS} = 16V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS		_	1	μA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	0.4	0.8	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		_	0.60	0.99		$V_{GS} = 4.5V, I_D = 100mA$	
		_	0.75	1.2		$V_{GS} = 2.5V, I_D = 50mA$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	0.90	1.8	Ω	$V_{GS} = 1.8V, I_D = 20mA$	
		_	1.2	2.4		V _{GS} = 1.5V, I _D = 10mA	
			2.0	_		$V_{GS} = 1.2V, I_D = 1mA$	
Diode Forward Voltage	V _{SD}		0.6	1.0	V	$V_{GS} = 0V, I_{S} = 150mA$	
DYNAMIC CHARACTERISTICS (Note 8)				•			
Input Capacitance	C _{iss}	_	21.5	_	pF		
Output Capacitance	Coss		4.9	_	pF	V _{DS} = 16V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss		3.7	_	pF		
Total Gate Charge	Qg	_	0.35	_	nC		
Gate-Source Charge	Q _{gs}	_	0.07	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$	
Gate-Drain Charge	Q _{gd}	_	0.08	_	nC	- I _D = 250mA	
Turn-On Delay Time	t _{D(ON)}	_	5.6	_	ns		
Turn-On Rise Time	t _R	_	4.9	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	60.6	—	ns	$R_{\rm L} = 47\Omega, R_{\rm g} = 10\Omega,$	
Turn-Off Fall Time	t _F	_	27.6	—	ns	$I_D = 200 \text{mA}$	
Reverse Recovery Time	t _{RR}	_	12.3	—	ns	I _F = 1.0A, di/dt = 100A/µs	
Reverse Recovery Charge	Q _{RR}		1.1	_	nC	I _F = 1.0A, di/dt = 100A/µs	

Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



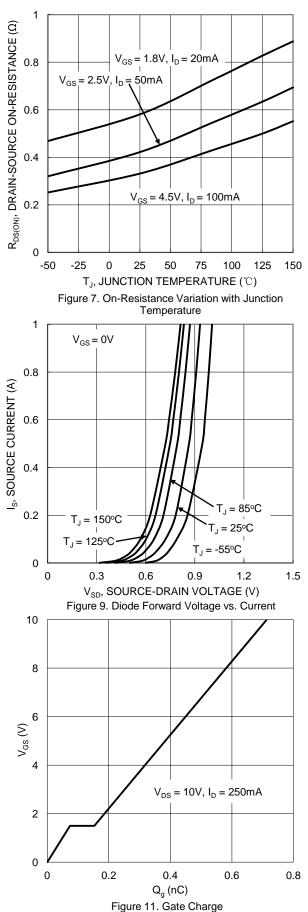
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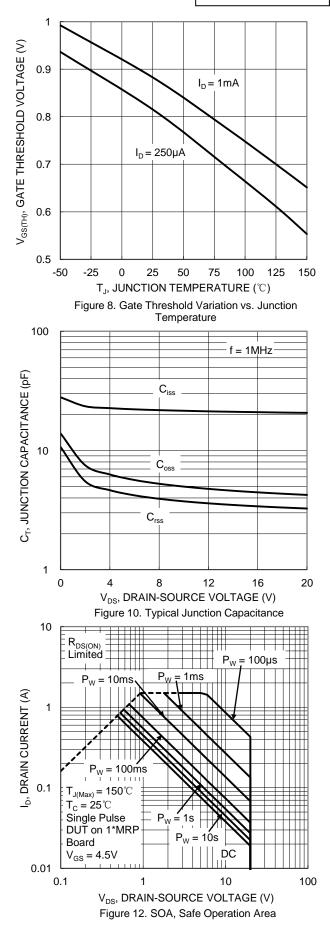


DMN2991UFZ Document number: DS41114 Rev. 3 - 2

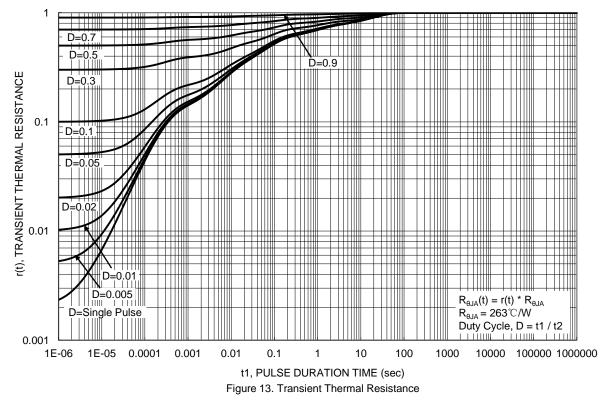


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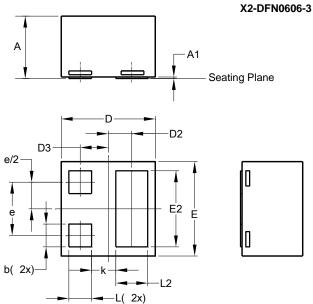






Package Outline Dimensions

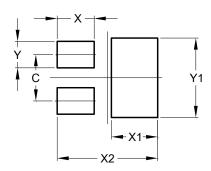
Please see http://www.diodes.com/package-outlines.html for the latest version.



X2-DFN0606-3					
Dim	Min Max Typ				
Α	0.36	0.42	0.39		
A1	0	0.05	0.02		
b	0.10	0.20	0.15		
D	0.57	0.67	0.62		
D2	0.155 BSC				
D3	0	0.185 BSC			
E	0.57	0.67	0.62		
E2	0.40	0.60	0.50		
e	0.35 BSC				
k	0.16 REF				
L	0.09	0.21	0.15		
L2	0.11	0.31	0.21		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



X2-DFN0606-3

Dimensions	Value (in mm)		
С	0.350		
Х	0.280		
X1	0.350		
X2	0.760		
Y	0.200		
Y1	0.600		



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